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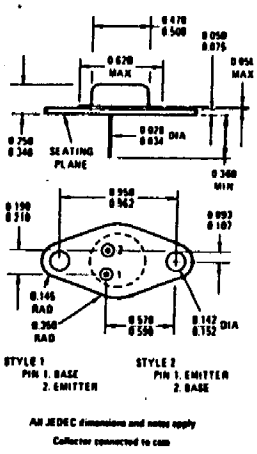
2N3767

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	2N3767	Unit
Collector-Base Voltage	V_{CB}	100	Vdc
Emitter-Base Voltage	V_{EB}	6.0	Vdc
Collector-Emitter Voltage	V_{CEO}	80	Vdc
Collector Current - Continuous Peak	I_C	4.0 4.0	Adc
Base Current	I_B	2.0	Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	20 0.133	Watts W/°C
Thermal Resistance	θ_{JC}	7.5	°C/W
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +175	°C

(TO-66)



ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Voltage [1] (I_C = 100 mAdc, I_B = 0)	BV_{CEO}	80	—	Vdc
Emitter-Base Cutoff Current (V_{EB} = 6 Vdc)	I_{EBO}	—	0.75	mAdc
Collector Cutoff Current	I_{CEX}			mAdc
(V_{CE} = 100 Vdc, V_{BE} = 1.5 Vdc)		—	0.1	
(V_{CE} = 70 Vdc, V_{BE} = 1.5 Vdc, T_C = 150°C)		—	1.0	
Collector-Emitter Cutoff Current	I_{CEO}			mAdc
(V_{CE} = 80 Vdc, I_B = 0)		—	0.7	
Collector-Base Cutoff Current	I_{CBO}			mAdc
(V_{CB} = 100 Vdc, I_E = 0)		—	0.1	
ON CHARACTERISTICS				
DC Current Gain	h_{FE}			—
(I_C = 50 mAdc, V_{CE} = 5 Vdc)		30	—	
(I_C = 500 mAdc, V_{CE} = 5 Vdc)		40	160	
(I_C = 1.0 Adc, V_{CE} = 10 Vdc)		20	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			Vdc
(I_C = 1 Adc, I_B = 0.1 Adc)		—	2.5	
(I_C = 500 mAdc, I_B = 50 mAdc)		—	1.0	
Base-Emitter Voltage (I_C = 1.0 Adc, V_{CE} = 10 Vdc)	V_{BE}	—	1.5	Vdc
TRANSIENT CHARACTERISTICS				
Current-Gain - Bandwidth Product (I_C = 500 mAdc, V_{CE} = 10 Vdc, f = 10 MHz)	f_T	10	—	MHz
Common-Base Output Capacitance (V_{CB} = 10 Vdc, I_C = 0 Adc, f = 100 kHz)	C_{ob}	—	50	pF
Small-Signal Current Gain (I_C = 100 mAdc, V_{CE} = 10 Vdc, f = 1 kHz)	h_{fe}	40	—	—

[1] Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%